

## In the United States Patent and Trademark Office

Serial No. PCT/EP2003/003136	§ 8	Date: 26 March 2003
Title: FORMATION OF THIN SEMI-	§	
CONDUCTOR LAYERS BY LOW-	§	
ENERGY PLASMA ENHANCED	§	
CHEMICAL VAPOR DEPOSITION	§	
AND SEMICONDUCTOR HETERO-	§	,
STRUCTURE DEVICES	§	
	§	Examiner: pending
	§	
Applicant: Von Kaenel, Hans	§	GA No.: pending
	§	
Atty docket no: PUS-E006-013	§	
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## PRE-AMENDMENT

## Via facsimile to 001-571-273-8300, to:

Commissioner for Patents P. O. Box 1450 Alexandria, Virginia 22313-1450 U.S.A.

Dear Sir:

Together with the filing of the US national stage application, Applicant requests that the following pre-amendments be entered before calculation of the fees due therefor:

In the Claims: